MUR3020WT, MUR3060WT

Preferred Devices

SWITCHMODE[™] Power Rectifiers

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 and 60 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-247 Package
- High Voltage Capability to 600 V
- Low Forward Drop
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating Specified @ Both Case and Ambient Temperatures
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- Pb–Free Packages are Available*

Mechanical Characteristics:

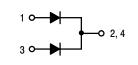
- Case: Epoxy, Molded
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 Units Per Plastic Tube



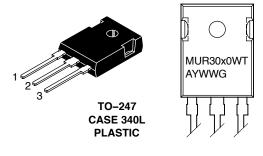
ON Semiconductor®

http://onsemi.com

ULTRAFAST RECTIFIERS 30 AMPERES, 200–600 VOLTS



MARKING DIAGRAM



MUR30x0WT = Device Code					
	x = 2 or 6				
А	= Assembly Location				
Y	= Year				
WW	= Work Week				
G	= Pb-Free Package				

ORDERING INFORMATION

Device	Package	Shipping
MUR3020WT	TO-247	30 Units/Rail
MUR3020WTG	TO–247 (Pb–Free)	30 Units/Rail
MUR3060WT	TO-247	30 Units/Rail
MUR3060WTG	TO-247 (Pb-Free)	30 Units/Rail

Preferred devices are recommended choices for future use

and best overall value.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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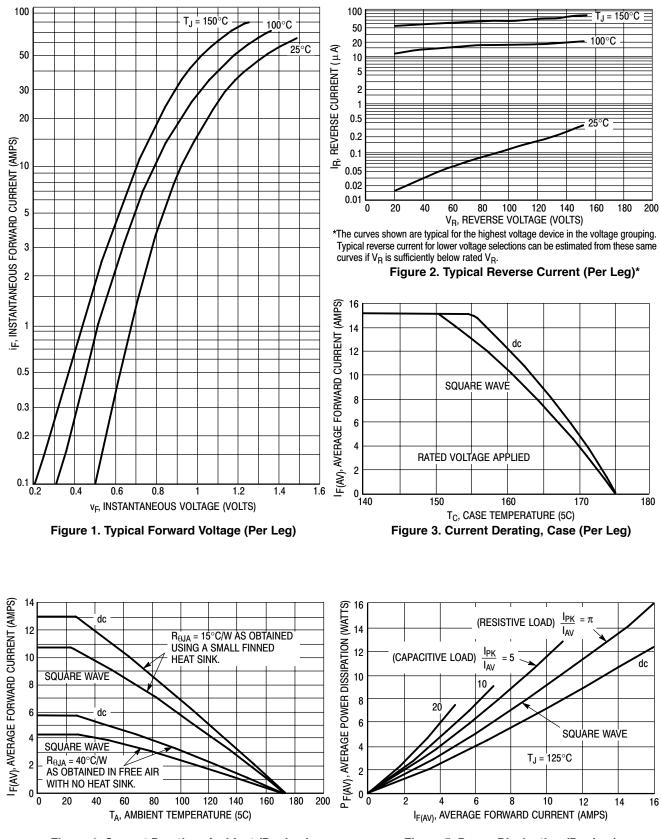
MAXIMUM RATINGS (Per Leg)

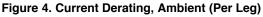
Rating	Symbol	MUR3020WT	MUR3060WT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	600	V
Average Rectified Forward Current @ 145°C Total Device	I _{F(AV)}	15 30		A
Peak Repetitive Surge Current (Rated V _R , Square Wave, 20 kHz, T _C = 145°C)	I _{FM}	30		А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I _{FSM}	200	150	A
Operating Junction and Storage Temperature	T _J , T _{stg}	– 65 to +175		°C
THERMAL CHARACTERISTICS (Per Leg)		·		
Maximum Thermal Resistance, – Junction-to-Case – Junction-to-Ambient	R _{θJC} R _{θJA}	1.5 40		°C/W
ELECTRICAL CHARACTERISTICS (Per Leg)		•		
Maximum Instantaneous Forward Voltage (Note 1) (I _F = 15 Amp, T _C = 150°C) (I _F = 15 Amp, T _C = 25°C)	V _F	0.85 1.05	1.4 1.7	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_J = 150^{\circ}C$) (Rated DC Voltage, $T_J = 25^{\circ}C$)	i _R	500 10	1000 10	μΑ
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 Amps/µs)	t _{rr}	35	60	ns

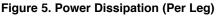
1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

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MUR3020WT

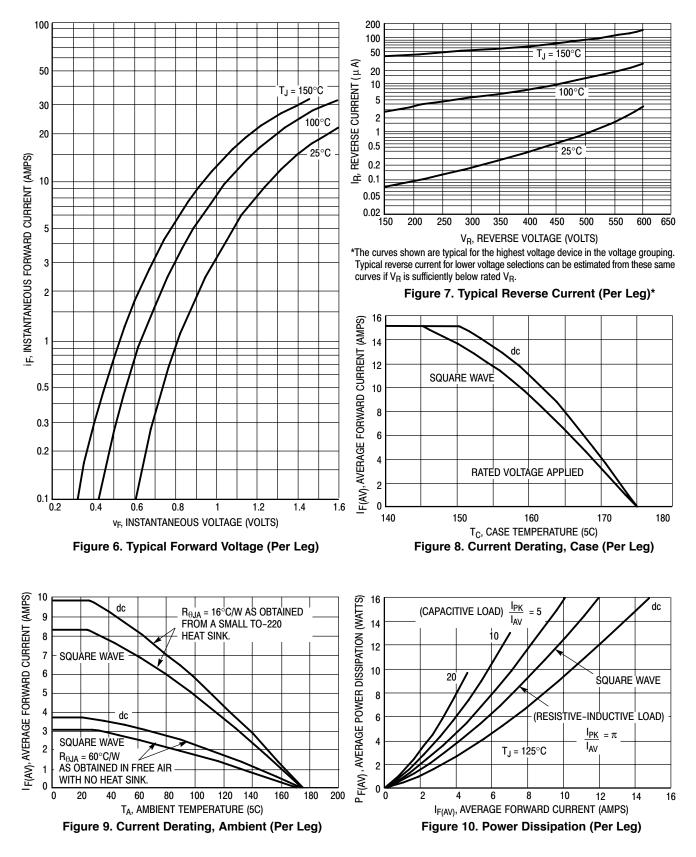




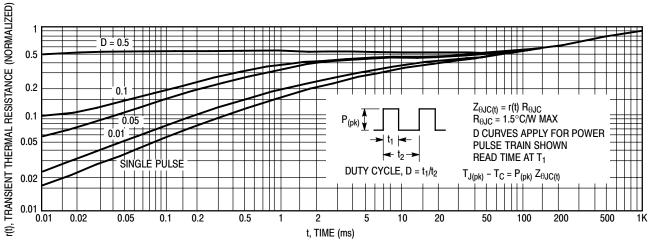


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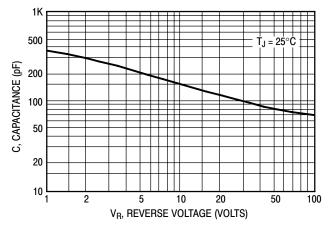
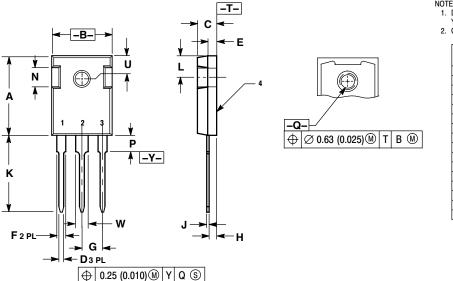


Figure 12. Typical Capacitance (Per Leg)

PACKAGE DIMENSIONS

TO-247 PSI CASE 340L-02 ISSUE D



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	20.32	21.08	0.800	8.30	
В	15.75	16.26	0.620	0.640	
С	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
Ε	2.20	2.60	0.087	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45 BSC		0.215 BSC		
Н	1.50	2.49	0.059	0.098	
J	0.40	0.80	0.016	0.031	
K	20.06	20.83	0.790	0.820	
L	5.40	6.20	0.212	0.244	
Ν	4.32	5.49	0.170	0.216	
Ρ		4.50		0.177	
Q	3.55	3.65	0.140	0.144	
U	6.15 BSC		0.242 BSC		
W	2.87	3.12	0.113	0.123	

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